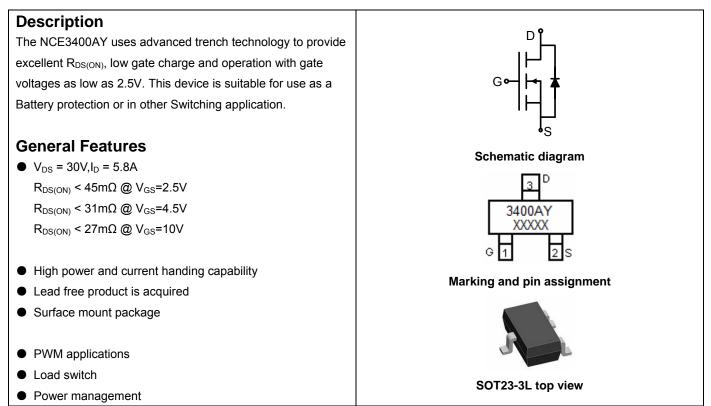


NCE N-Channel Enhancement Mode Power MOSFET



Package Marking and Ordering Information

 V	<u> </u>	V			
Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
3400AY	NCE3400AY	SOT23-3L	Ø180mm	8 mm	3000 units

Absolute Maximum Ratings (T_A=25℃ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	Vds	30	V
Gate-Source Voltage	Vgs	±12	V
Drain Current-Continuous	Ι _D	5.8	А
Drain Current-Pulsed (Note 1)	I _{DM}	30	A
Maximum Power Dissipation	PD	1.4	W
Operating Junction and Storage Temperature Range	TJ,TSTG	-55 To 150	°C

Thermal Characteristic

Thermal Resistance, Junction-to-Ambient (Note 2)	R _{0JA}	89	°C /W
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Electrical Characteristics (T_A=25[°]C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250µA	30	33	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} =30V, V_{GS} =0V	-	-	1	μA

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Parameter	Symbol	Condition	Min	Тур	Мах	Unit
Gate-Body Leakage Current	I _{GSS}	V_{GS} =±12V, V_{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)			•			
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	0.7	0.9	1.4	V
		V _{GS} =2.5V, I _D =4A	-	24	45	mΩ
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =4.5V, I _D =5A	-	21	31	mΩ
		V _{GS} =10V, I _D =5.8A	-	20	27	mΩ
Forward Transconductance	g fs	V _{DS} =5V,I _D =5A	10	-	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C _{lss}		-	825	-	PF
Output Capacitance	Coss	V _{DS} =15V,V _{GS} =0V, F=1.0MHz	-	100	-	PF
Reverse Transfer Capacitance	C _{rss}		-	78	-	PF
Switching Characteristics (Note 4)	· · ·					
Turn-on Delay Time	t _{d(on)}		-	3.3	-	nS
Turn-on Rise Time	tr	V_{DD} =15V, R _L =2.7 Ω	-	4.8	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =10V, R_{GEN} =3 Ω	-	26	-	nS
Turn-Off Fall Time	t _f		-	4	-	nS
Total Gate Charge	Qg		-	10	-	nC
Gate-Source Charge	Q _{gs}	V_{DS} =15V,I _D =5.8A,	-	1.6	-	nC
Gate-Drain Charge	Q _{gd}	V _{GS} =4.5V	-	3.1	-	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =5.8A	-	-	1.2	V
Diode Forward Current (Note 2)	I _S		-	-	5.8	Α

Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

2. Surface Mounted on FR4 Board, t \leq 10 sec.

- **3.** Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2%.
- 4. Guaranteed by design, not subject to production



Typical Electrical and Thermal Characteristics

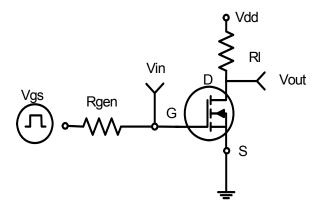
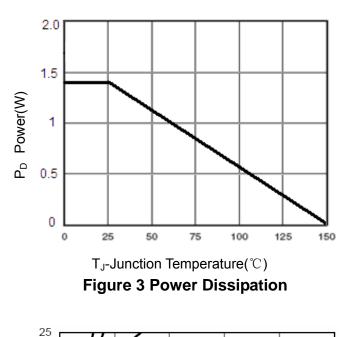
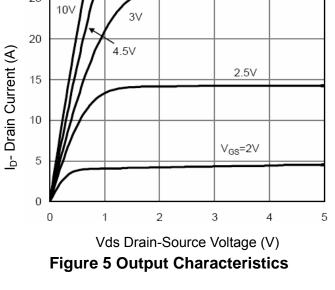


Figure 1:Switching Test Circuit





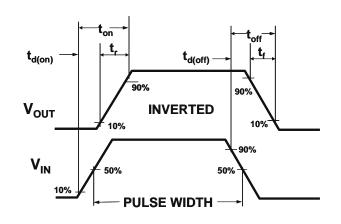
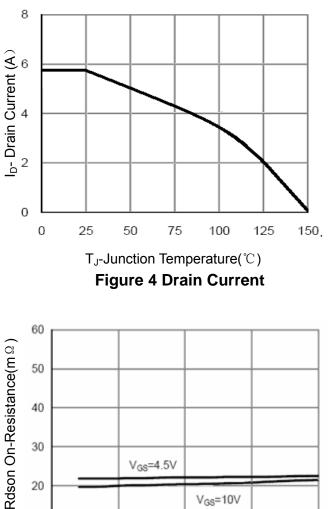
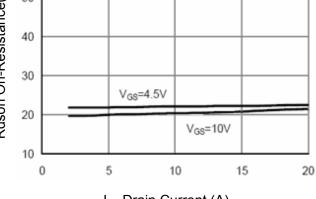


Figure 2:Switching Waveforms



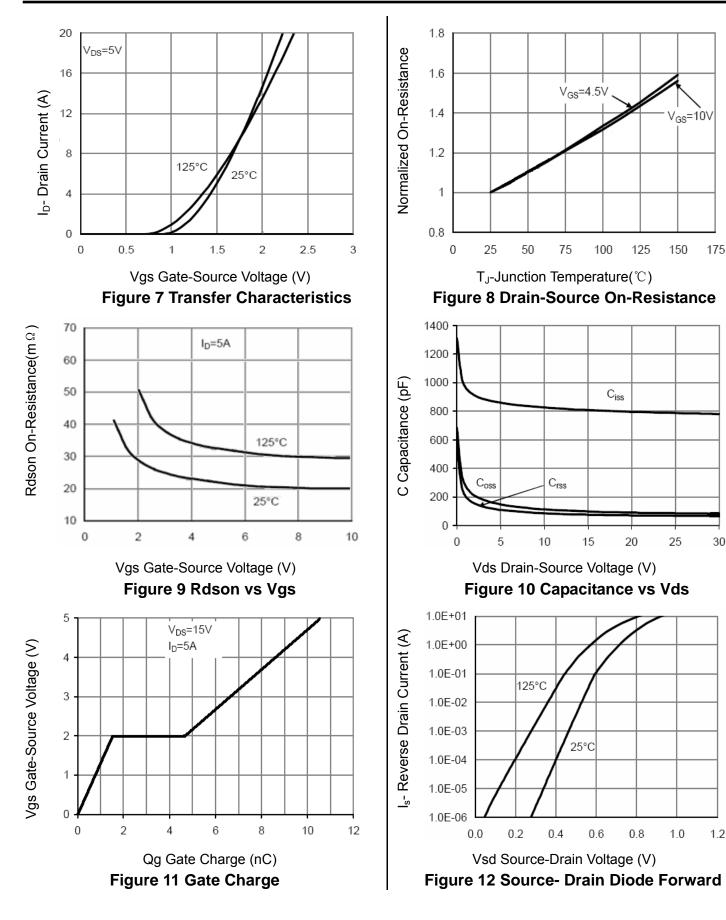


I_D- Drain Current (A) Figure 6 Drain-Source On-Resistance



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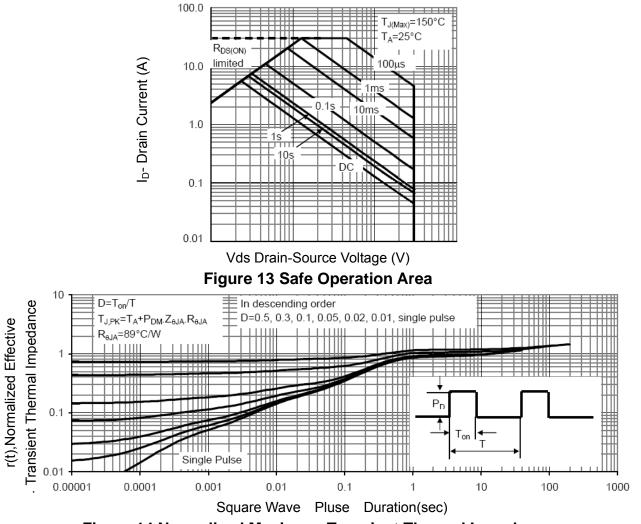
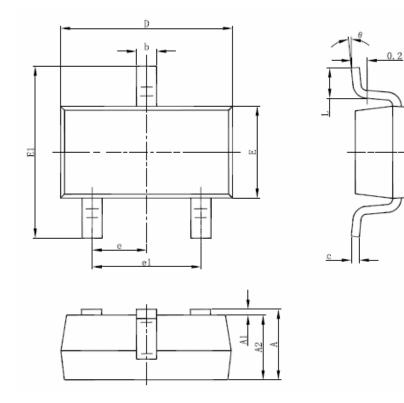


Figure 14 Normalized Maximum Transient Thermal Impedance



SOT-23-3L Package Information



Symbol	Dimensions Ir	n Millimeters	Dimensions In Inches		
Symbol	Min	Max	Min	Max	
A	1.050	1.250	0.041	0.049	
A1	0.000	0.100	0.000	0.004	
A2	1.050	1.150	0.041	0.045	
b	0.300	0.500	0.012	0.020	
с	0.100	0.200	0.004	0.008	
D	2.820	3.020	0.111	0.119	
E	1.500	1.700	0.059	0.067	
E1	2.650	2.950	0.104	0.116	
е	0.950	(BSC)	0.037(BSC)	
e1	1.800	2.000	0.071	0.079	
L	0.300	0.600	0.012	0.024	
θ	0°	8°	0°	8°	

Notes

- 1. All dimensions are in millimeters.
- 2. Tolerance ±0.10mm (4 mil) unless otherwise specified
- 3. Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 5 mils.
- 4. Dimension L is measured in gauge plane.
- 5. Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.

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